



Sample &

Buy





LM60, LM60-Q1

SNIS119E - MAY 2004 - REVISED SEPTEMBER 2015

# LM60 and LM60-Q1 2.7-V, SOT-23 or TO-92 Temperature Sensor

### 1 Features

- Calibrated Linear Scale Factor of 6.25 mV/°C
- Rated for Full -40°C to +125°C Range
- Suitable for Remote Applications
- Available in SOT-23 and TO-92 Packages
- LM60-Q1 is AEC-Q100 Grade 1 Qualified and is Manufactured on an Automotive Grade Flow.
- Key Specifications
  - Accuracy at 25°C: ± 2°C and ± 3°C (Maximum)
  - Accuracy for -40°C to +125°C: ±4°C (Maximum)
  - Accuracy for -25°C to +125°C: ±3°C (Maximum)
  - Temperature Slope: 6.25 mV/°C
  - Power-Supply Voltage Range: 2.7 V to 10 V
  - Current Drain at 25°C: 110 μA (Maximum)
  - Nonlinearity: ±0.8°C (Maximum)
  - Output Impedance: 800 Ω (Maximum)

### 2 Applications

- Automotive
- Cell Phones and Computers
- Power Supply Modules
- Battery Management
- Fax Machines and Printers
- HVAC and Disk Drives
- Appliances



### 3 Description

The LM60 and LM60-Q1 devices are precision integrated-circuit temperature sensors that can sense a -40°C to +125°C temperature range while operating from a single 2.7-V supply. The output voltage of the device is linearly proportional to Celsius (Centigrade) temperature (6.25 mV/°C) and has а DC offset of 424 mV. The offset allows reading negative temperatures without the need for a negative supply. The nominal output voltage of the device ranges from 174 mV to 1205 mV for a -40°C to +125°C temperature range. The device is calibrated to provide accuracies of ±2°C at room temperature and ±3°C over the full -25°C to +125°C temperature range.

The linear output of the device, 424-mV offset, and factory calibration simplify external circuitry required in a single supply environment where reading negative temperatures is required. Because the quiescent current of the device is less than 110  $\mu$ A, self-heating is limited to a very low 0.1°C in still air in the SOT-23 package. Shutdown capability for the device is intrinsic because its inherent low power consumption allows it to be powered directly from the output of many logic gates.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
	TO-92 (3)	4.30 mm × 4.30 mm
LIVIOU	SOT-23 (3)	2.92 mm × 1.30 mm
LM60 LM60-Q1	SOT-23 (3)	2.92 mm × 1.30 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Full-Range Centigrade Temperature Sensor (-40°C to +125°C)



2

# **Table of Contents**

1	Feat	tures 1
2	Арр	lications 1
3	Des	cription 1
4	Rev	ision History 2
5	Dev	ice Comparison Table 3
6	Pin	Configuration and Functions 4
7	Spe	cifications 4
	7.1	Absolute Maximum Ratings 4
	7.2	ESD Ratings 4
	7.3	Recommended Operating Conditions 5
	7.4	Thermal Information 5
	7.5	Electrical Characteristics5
	7.6	Typical Characteristics 7
8	Deta	ailed Description
	8.1	Overview
	8.2	Functional Block Diagram9
	8.3	Feature Description9

9	App	lication and Implementation	10
	9.1	Application Information	10
	9.2	Typical Applications	11
	9.3	System Examples	13
10	Pow	ver Supply Recommendations	13
11	Lay	out	13
	11.1	Layout Guidelines	13
	11.2	Layout Example	14
	11.3	Thermal Considerations	14
12	Dev	ice and Documentation Support	16
	12.1	Related Links	16
	12.2	Community Resources	16
	12.3	Trademarks	16
	12.4	Electrostatic Discharge Caution	16
	12.5	Glossary	16
13	Мес	hanical, Packaging, and Orderable	
	Infor	mation	16

### **4** Revision History

#### Changes from Revision D (November 2012) to Revision E

Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional • Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device 

Product Folder Links: LM60 LM60-Q1



www.ti.com

Page



# 5 Device Comparison Table

ORDER NUMBER	ACCURACY OVER SPECIFIED TEMPERATURE RANGE	SPECIFIED TEMPERATURE RANGE
LM60BIM3	±3	$-25^{\circ}C \le T_A \le +125^{\circ}C$
LM60BIM3X		
LM60CIM3	±4	$-40^{\circ}C \le T_A \le +125^{\circ}C$
LM60CIM3X		
LM60QIM3	±4	$-40^{\circ}C \le T_A \le +125^{\circ}C$
LM60QIM3X		
LM60BIZ	±3	$-25^{\circ}C \le T_A \le +125^{\circ}C$
LM60CIZ	±4	$-40^{\circ}C \le T_A \le +125^{\circ}C$

### 6 Pin Configuration and Functions



LP Package 3-Pin TO-92 Bottom View

#### **Pin Functions**

PIN			TYPE	DESCRIPTION
NAME	SOT-23 NO.	TO92 NO.	TIPE	DESCRIPTION
GND	3	3	GND	Device ground, connected to power supply negative terminal
V <sub>OUT</sub>	2	2	0	Temperature sensor analog output
+V <sub>S</sub>	1	1	POWER	Positive power supply pin

### 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

	MIN	MAX	UNIT
Supply voltage	-0.2	12	V
Output voltage	-0.6	V <sub>S</sub> + 0.6	V
Output current		10	mA
Input current at any pin <sup>(2)</sup>		5	mA
Maximum junction temperature (T <sub>JMAX</sub> )		125	°C
Storage temperature (T <sub>stg</sub> )	-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) When the input voltage ( $V_1$ ) at any pin exceeds power supplies ( $V_1 < GND$  or  $V_1 > +V_S$ ), the current at that pin should be limited to 5 mA.

### 7.2 ESD Ratings

			VALUE	UNIT		
LM60 in	DBZ Package					
V <sub>(ESD)</sub> Electrostatic discharge <sup>(1)</sup>	Human-body model (HBM)	±2500	V			
	Machine Model (MM)	±250				
LM60 in	LM60 in LP Package					
V <sub>(ESD)</sub> Electrostatic discha	Electroptotic discharge <sup>(1)</sup>	Human-body model (HBM)	±2500	V		
	Electrostatic discharge /	Machine Model (MM)	±200	V		

(1) The human body model is a 100-pF capacitor discharged through a 1.5-kΩ resistor into each pin. The machine model is a 200-pF capacitor discharged directly into each pin.



### 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

	MIN	MAX	UNIT
LM60B ( $T_{MIN} \le T_A \le T_{MAX}$ )	-25	125	°C
LM60C/LM60-Q1 ( $T_{MIN} \le T_A \le T_{MAX}$ )	-40	125	°C
Supply Voltage (+V <sub>S</sub> )	2.7	10	V

(1) Soldering process must comply with National Semiconductor's Reflow Temperature Profile specifications. Refer to www.national.com/packaging. Reflow temperature profiles are different for lead-free and non-lead-free packages.

### 7.4 Thermal Information

		LM60/LM60-Q1	LM60	
	THERMAL METRIC <sup>(1)</sup>	DBZ (SOT-23)	LP (TO-92)	UNIT
		3 PINS	3 PINS	
$R_{\theta JA}^{(2)}$	Junction-to-ambient thermal resistance	266	162	°C/W
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	135	85	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	59	_	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	18	29	°C/W
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	58	142	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor or IC Package Thermal Metrics application report, SPRA953.

(2) The junction to ambient thermal resistance  $(R_{\theta JA})$  is specified without a heat sink in still air.

### 7.5 Electrical Characteristics

Unless otherwise noted, these specifications apply for +V<sub>S</sub> = 3 V<sub>DC</sub> and I<sub>LOAD</sub> = 1  $\mu$ A. All limits T<sub>A</sub> = T<sub>J</sub> = 25°C unless otherwise noted.

PARAMETER	TEST CONDITIONS		MIN <sup>(1)</sup>	TYP <sup>(2)</sup>	MAX <sup>(1)</sup>	UNIT
			-2		2	
Accuracy ( <sup>3)</sup>	LM60B		-3		3	°C
Accuracy			-3		3	
	LM60C/LM60-Q1		-4		4	°C
Output Voltage at 0°C				424		mV
Nonlinearity <sup>(4)</sup>	LM60B		-0.6		±0.6	*
noninearry	LM60C/LM60-Q1	$T_A = T_J = T_{MIN}$ to $T_{MAX}$	-0.8		±0.8	
				6.25		
Sensor Gain (Average Slope)	LM60B	$T_A = T_J = T_{MIN}$ to $T_{MAX}$	6.06		6.44	mV/°C
	LM60C/LM60-Q1		6		6.5	
Output Impedance	$T_A = T_J = T_{MIN}$ to $T_{MAX}$				800	Ω
Line Regulation <sup>(5)</sup>	$3 \text{ V} \leq +\text{V}_{\text{S}} \leq 10 \text{ V}$		-0.3		0.3	mV/V
	$2.7 \text{ V} \leq +\text{V}_{S} \leq 3.3 \text{ V}$	$T_A = T_J = T_{MIN}$ to $T_{MAX}$	-2.3		2.3	mV

(1) Limits are specified to TI's AOQL (Average Outgoing Quality Level).

(2) Typicals are at  $T_J = T_A = 25^{\circ}C$  and represent most likely parametric norm.

(3) Accuracy is defined as the error between the output voltage and 6.25 mV/°C times the case temperature of the device plus 424 mV, at specified conditions of voltage, current, and temperature (expressed in °C).

(4) Nonlinearity is defined as the deviation of the output-voltage-versus-temperature curve from the best-fit straight line, over the rated temperature range of the device.

(5) Regulation is measured at constant junction temperature, using pulse testing with a low duty cycle. Changes in output due to heating effects can be computed by multiplying the internal dissipation by the thermal resistance.

Copyright © 2004–2015, Texas Instruments Incorporated



### **Electrical Characteristics (continued)**

Unless otherwise noted, these specifications apply for +V<sub>S</sub> = 3 V<sub>DC</sub> and I<sub>LOAD</sub> = 1  $\mu$ A. All limits T<sub>A</sub> = T<sub>J</sub> = 25°C unless otherwise noted.

PARAMETER	TEST COND	TEST CONDITIONS		TYP <sup>(2)</sup>	MAX <sup>(1)</sup>	UNIT
				82	110	μA
Quiescent Current	$2.7 \text{ V} \leq +\text{V}_{S} \leq 10 \text{ V}$	$T_A = T_J = T_{MIN}$ to $T_{MAX}$			125	μA
Change of Quiescent Current	$2.7 \text{ V} \leq +\text{V}_{S} \leq 10 \text{ V}$			±5		μA
Temperature Coefficient of Quiescent Current				0.2		µA/°C
Long Term Stability <sup>(6)</sup>	$T_J = T_{MAX} = 125^{\circ}C$ for 1000 hours			±0.2		°C

(6) For best long-term stability, any precision circuit will give best results if the unit is aged at a warm temperature, temperature cycled for at least 46 hours before long-term life test begins for both temperatures. This is especially true when a small (surface-mount) part is wave-soldered; allow time for stress relaxation to occur. The majority of the drift will occur in the first 1000 hours at elevated temperatures. The drift after 1000 hours will not continue at the first 1000 hour rate.



### 7.6 Typical Characteristics

To generate these curves, the device was mounted to a printed-circuit-board as shown in Figure 20.



#### LM60, LM60-Q1

SNIS119E-MAY 2004-REVISED SEPTEMBER 2015

www.ti.com

**ISTRUMENTS** 

EXAS

### **Typical Characteristics (continued)**

To generate these curves, the device was mounted to a printed-circuit-board as shown in Figure 20.



Copyright © 2004–2015, Texas Instruments Incorporated



### 8 Detailed Description

The LM60 and LM60-Q1 devices are precision analog bipolar temperature sensors that can sense a -40°C to +125°C temperature range while operating from a single 2.7-V supply. The output voltage of the LM60 and LM60-Q1 is linearly proportional to Celsius (Centigrade) temperature (6.25 mV/°C) and has a DC offset of 424 mV. The offset allows reading negative temperatures with a single positive supply. The nominal output voltage of the device ranges from 174 mV to 1205 mV for a -40°C to +125°C temperature range. The device is calibrated to provide accuracies of  $\pm 2.0^{\circ}$ C at room temperature and  $\pm 3^{\circ}$ C over the full -25°C to +125°C temperature range.

With a quiescent current of the device is less than 110  $\mu$ A, self-heating is limited to a very low 0.1°C in still air in the SOT-23 package. Shutdown capability for the device is intrinsic because its inherent low power consumption allows it to be powered directly from the output of many logic gates.

The output of the LM60 and LM60-Q1 is a Class A base emitter follower, thus the LM60 and LM60-Q1 can source quite a bit of current while sinking less than 1  $\mu$ A. In any event load current should be minimized in order to limit it's contribution to the total temperature error. The temperature-sensing element is based on a delta V<sub>BE</sub> topology of two transistors (Q1 and Q2 in *Functional Block Diagram*) that are sized with a 10:1 area ratio.

### 8.2 Functional Block Diagram



#### 8.3 Feature Description

#### 8.3.1 LM60 Transfer Function

The LM60 follows a simple linear transfer function to achieve the accuracy as listed in *Electrical Characteristics* as given:

 $V_0 = (6.25 \text{ mV/}^{\circ}\text{C} \times \text{T} \circ \text{C}) + 424 \text{ mV}$ 

where

- T is the temperature
- $V_{O}$  is the LM60 output voltage

(1)

### 8.4 Device Functional Modes

The device's only functional mode is that it has an analog output directly proportional to temperature.



### 9 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### 9.1 Application Information

The device has low supply current and wide supply range therefore it can easily be driven by a battery.

#### 9.1.1 Capacitive Loads

The device handles capacitive loading well. Without any special precautions, the device can drive any capacitive load as shown in Figure 12. Over the specified temperature range the device has a maximum output impedance of 800  $\Omega$ . In an extremely noisy environment adding some filtering to minimize noise pick-up could be required. TI recommends that 0.1 µF be added from +V<sub>S</sub> to GND to bypass the power supply voltage, as shown in Figure 13. In a noisy environment, adding a capacitor from the output to ground. A 1-µF output capacitor with the 800- $\Omega$  output impedance will form a 199-Hz lowpass filter. Because the thermal time constant of the device is much slower than the 6.3-ms time constant formed by the RC, the overall response time of the device is not be significantly affected. For much larger capacitors this additional time lag increases the overall response time of the device.







Figure 13. Filter Added for Noisy Environment



#### 9.2 Typical Applications

#### 9.2.1 Full-Range Centigrade Temperature Sensor

Because the LM60 is a simple temperature sensor that provides an analog output, design requirements related to the layout are also important. Refer to *Layout* for details.



 $V_0 = (6.25 \text{ mV/}^{\circ}\text{C} \times \text{T}^{\circ}\text{C}) + 424 \text{ mV}$ 

Figure 14. Full-Range Centigrade Temperature Sensor (-40°C to +125°C) Operating from a Single Li-Ion Battery Cell

#### 9.2.1.1 Design Requirements

For this design example, use the design parameters listed in Table 1.

Figure 14				
TEMPERATURE (T)	TYPICAL Vo			
125°C	1205 mV			
100°C	1049 mV			
25°C	580 mV			
0°C	424 mV			
–25°C	268 mV			
-40°C	174 mV			

# Table 1. Temperature and Typical V<sub>o</sub> Values of Figure 14

#### 9.2.1.2 Detailed Design Procedure

Selection of the LM60 is based on the output voltage transfer function being able to meet the needs of the rest of the system.

#### 9.2.1.3 Application Curve







#### 9.2.2 Centigrade Thermostat Application



Figure 16. Centigrade Thermostat

#### 9.2.2.1 Design Requirements

A simple thermostat can be created by using a reference (LM4040) and a comparator (LM7211) as shown in Figure 16.

### 9.2.2.2 Detailed Design Procedure

Use Equation 2 and Equation 3 to calculate the threshold values for T1 and T2.

V <sub>T1</sub> =	(4.1)R2 R2 + R1  R3	(2)
V <sub>T2</sub> =	(4.1)R2  R3 R1 + R2  R3	(3)

#### 9.2.2.3 Application Curve



Figure 17. Thermostat Output Waveform



#### 9.3 System Examples

#### 9.3.1 Conserving Power Dissipation With Shutdown

The LMT89 draws very little power therefore it can simply be shutdown by driving the LMT89 supply pin with the output of a logic gate as shown in Figure 18.



Figure 18. Conserving Power Dissipation With Shutdown

### **10** Power Supply Recommendations

In an extremely noisy environment, adding some filtering to minimize noise pick-up. Adding 0.1  $\mu$ F from +V<sub>S</sub> to GND is recommended to bypass the power supply voltage, as shown in Figure 13. In a noisy environment adding a capacitor from the output to ground.

### 11 Layout

#### 11.1 Layout Guidelines

The LM60 and LM60-Q1 can be applied easily in the same way as other integrated-circuit temperature sensors. It can be glued or cemented to a surface. The temperature that the LM60 and LM60-Q1 is sensing will be within about +0.1°C of the surface temperature that the leads of th LM60 and LM60-Q1 are attached to.

This presumes that the ambient air temperature is almost the same as the surface temperature. If the air temperature were much higher or lower than the surface temperature, the actual temperature of the device die would be at an intermediate temperature between the surface temperature and the air temperature.

To ensure good thermal conductivity the backside of the device die is directly attached to the GND pin. The lands and traces to the device will, of course, be part of the printed-circuit-board, which is the object whose temperature is being measured. These printed-circuit-board lands and traces do not cause the temperature of the device to deviate from the desired temperature.

Alternatively, the device can be mounted inside a sealed-end metal tube, and can then be dipped into a bath or screwed into a threaded hole in a tank. As with any IC, the device and accompanying wiring and circuits must be kept insulated and dry to avoid leakage and corrosion. Specifically when the device operates at cold temperatures where condensation can occur. Printed-circuit coatings and varnishes such as a conformal coating and epoxy paints or dips are often used to ensure that moisture cannot corrode the device or connections.

TEXAS INSTRUMENTS

www.ti.com

#### 11.2 Layout Example



1/2-inch square printed circuit board with 2 oz. copper foil or similar.

#### Figure 19. PCB Layout

### **11.3 Thermal Considerations**

The thermal resistance junction to ambient ( $R_{\theta JA}$ ) is the parameter used to calculate the rise of a device junction temperature due to the device power dissipation. Use Equation 4 to calculate the rise in the die temperature of the device.

 $T_J = T_A + R_{\theta JA} [(+V_S I_Q) + (+V_S - V_O) I_L]$ 

where

- I<sub>Q</sub> is the quiescent current
- $I_L$  is the load current on the output

(4)

Table 2 summarizes the rise in die temperature of the LM60 and LM60-Q1 without any loading, and the thermal resistance for different conditions. The values in Table 2 were actually measured where as the values shown in Thermal Information where calculated using modeling methods as described in the *Semiconductor and IC Package Thermal Metrics* application report, SPRA953.

	SOT- NO HEA	-23 <sup>(1)</sup> AT SINK	SOT SMALL F	-23 <sup>(2)</sup> IEAT FIN	TO- NO HE	92 <sup>(1)</sup> AT FIN	TO-92 <sup>(3)</sup> SMALL HEAT FIN		
	R <sub>0JA</sub> T <sub>J</sub> – T <sub>A</sub>		R <sub>0JA</sub>	$T_J - T_A$	R <sub>0JA</sub>	$T_J - T_A$	R <sub>θJA</sub>	$T_J - T_A$	
	(°C/W)	(°C)	(°C/W)	(°C)	(°C/W)	(°C)	(°C/W)	(°C)	
Still air	450	0.17	260	0.1	180	0.07	140	0.05	
Moving air			180	0.07	90	0.034	70	0.026	

#### Table 2. Temperature Rise of LM60/LM60-Q1 Due to Self-Heating and Thermal Resistance (R<sub>8,JA</sub>)

(1) Part soldered to 30 gauge wire.

(2) Heat sink used is 1/2-in square printed-circuit-board with 2-oz. foil with part attached as shown in Figure 20.

(3) Part glued or leads soldered to 1-in square of 1/16-in printed-circuit-board with 2-oz. foil or similar.





1/2-in Square Printed-Circuit-Board with 2-oz. Copper Foil or Similar.

Figure 20. Printed-Circuit-Board Used for Heat Sink to Generate Thermal Response Curves



### **12 Device and Documentation Support**

#### 12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
LM60	Click here	Click here	Click here	Click here	Click here
LM60-Q1	Click here	Click here	Click here	Click here	Click here

#### Table 3. Related Links

#### **12.2 Community Resources**

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E<sup>™</sup> Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support TI's Design Support** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 12.3 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

#### 12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 12.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

### 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



23-Aug-2015

# PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
LM60BIM3	NRND	SOT-23	DBZ	3	1000	TBD	Call TI	Call TI	-25 to 125	Т6В	
LM60BIM3/NOPB	ACTIVE	SOT-23	DBZ	3	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-25 to 125	Т6В	Samples
LM60BIM3X	NRND	SOT-23	DBZ	3	3000	TBD	Call TI	Call TI	-25 to 125	T6B	
LM60BIM3X/NOPB	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-25 to 125	Т6В	Samples
LM60BIZ/LFT3	ACTIVE	TO-92	LP	3	2000	Green (RoHS & no Sb/Br)	CU SN	N / A for Pkg Type		LM60 BIZ	Samples
LM60BIZ/NOPB	ACTIVE	TO-92	LP	3	1800	Green (RoHS & no Sb/Br)	CU SN	N / A for Pkg Type	-25 to 125	LM60 BIZ	Samples
LM60CIM3	NRND	SOT-23	DBZ	3	1000	TBD	Call TI	Call TI	-40 to 125	T6C	
LM60CIM3/NOPB	ACTIVE	SOT-23	DBZ	3	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	T6C	Samples
LM60CIM3X	NRND	SOT-23	DBZ	3	3000	TBD	Call TI	Call TI	-40 to 125	T6C	
LM60CIM3X/NOPB	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	T6C	Samples
LM60CIZ/NOPB	ACTIVE	TO-92	LP	3	1800	Green (RoHS & no Sb/Br)	CU SN	N / A for Pkg Type	-40 to 125	LM60 CIZ	Samples
LM60QIM3/NOPB	ACTIVE	SOT-23	DBZ	3	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L60Q	Samples
LM60QIM3X/NOPB	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L60Q	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.



# PACKAGE OPTION ADDENDUM

23-Aug-2015

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above. Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(<sup>5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF LM60, LM60-Q1 :

Catalog: LM60

Automotive: LM60-Q1

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

# PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

### TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM60BIM3	SOT-23	DBZ	3	1000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM60BIM3/NOPB	SOT-23	DBZ	3	1000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM60BIM3X	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM60BIM3X/NOPB	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM60CIM3	SOT-23	DBZ	3	1000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM60CIM3/NOPB	SOT-23	DBZ	3	1000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM60CIM3X	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM60CIM3X/NOPB	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM60QIM3/NOPB	SOT-23	DBZ	3	1000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM60QIM3X/NOPB	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3

Texas Instruments

www.ti.com

# PACKAGE MATERIALS INFORMATION

6-Mar-2015



*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM60BIM3	SOT-23	DBZ	3	1000	210.0	185.0	35.0
LM60BIM3/NOPB	SOT-23	DBZ	3	1000	210.0	185.0	35.0
LM60BIM3X	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM60BIM3X/NOPB	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM60CIM3	SOT-23	DBZ	3	1000	210.0	185.0	35.0
LM60CIM3/NOPB	SOT-23	DBZ	3	1000	210.0	185.0	35.0
LM60CIM3X	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM60CIM3X/NOPB	SOT-23	DBZ	3	3000	210.0	185.0	35.0
LM60QIM3/NOPB	SOT-23	DBZ	3	1000	210.0	185.0	35.0
LM60QIM3X/NOPB	SOT-23	DBZ	3	3000	210.0	185.0	35.0

# **GENERIC PACKAGE VIEW**

# TO-92 - 5.34 mm max height TRANSISTOR OUTLINE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



# LP0003A



# **PACKAGE OUTLINE**

## TO-92 - 5.34 mm max height

TO-92



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- Lead dimensions are not controlled within this area.
  Reference JEDEC TO-226, variation AA.
- 5. Shipping method:

  - a. Straight lead option available in bulk pack only.b. Formed lead option available in tape and reel or ammo pack.
  - c. Specific products can be offered in limited combinations of shipping medium and lead options.
  - d. Consult product folder for more information on available options.



# LP0003A

# **EXAMPLE BOARD LAYOUT**

# TO-92 - 5.34 mm max height

TO-92





# LP0003A

# TAPE SPECIFICATIONS

# TO-92 - 5.34 mm max height

TO-92





# DBZ 3

# **GENERIC PACKAGE VIEW**

# SOT-23 - 1.12 mm max height SMALL OUTLINE TRANSISTOR



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



4203227/C

# **DBZ0003A**



# **PACKAGE OUTLINE**

# SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC registration TO-236, except minimum foot length.



# **DBZ0003A**

# **EXAMPLE BOARD LAYOUT**

# SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# DBZ0003A

# **EXAMPLE STENCIL DESIGN**

# SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

7. Board assembly site may have different recommendations for stencil design.

![](_page_27_Picture_8.jpeg)

#### **IMPORTANT NOTICE**

Texas Instruments Incorporated (TI) reserves the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete.

TI's published terms of sale for semiconductor products (http://www.ti.com/sc/docs/stdterms.htm) apply to the sale of packaged integrated circuit products that TI has qualified and released to market. Additional terms may apply to the use or sale of other types of TI products and services.

Reproduction of significant portions of TI information in TI data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such reproduced documentation. Information of third parties may be subject to additional restrictions. Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyers and others who are developing systems that incorporate TI products (collectively, "Designers") understand and agree that Designers remain responsible for using their independent analysis, evaluation and judgment in designing their applications and that Designers have full and exclusive responsibility to assure the safety of Designers' applications and compliance of their applications (and of all TI products used in or for Designers' applications) with all applicable regulations, laws and other applicable requirements. Designer represents that, with respect to their applications, Designer has all the necessary expertise to create and implement safeguards that (1) anticipate dangerous consequences of failures, (2) monitor failures and their consequences, and (3) lessen the likelihood of failures that might cause harm and take appropriate actions. Designer agrees that prior to using or distributing any applications that include TI products, Designer will thoroughly test such applications and the functionality of such TI products as used in such applications.

TI's provision of technical, application or other design advice, quality characterization, reliability data or other services or information, including, but not limited to, reference designs and materials relating to evaluation modules, (collectively, "TI Resources") are intended to assist designers who are developing applications that incorporate TI products; by downloading, accessing or using TI Resources in any way, Designer (individually or, if Designer is acting on behalf of a company, Designer's company) agrees to use any particular TI Resource solely for this purpose and subject to the terms of this Notice.

TI's provision of TI Resources does not expand or otherwise alter TI's applicable published warranties or warranty disclaimers for TI products, and no additional obligations or liabilities arise from TI providing such TI Resources. TI reserves the right to make corrections, enhancements, improvements and other changes to its TI Resources. TI has not conducted any testing other than that specifically described in the published documentation for a particular TI Resource.

Designer is authorized to use, copy and modify any individual TI Resource only in connection with the development of applications that include the TI product(s) identified in such TI Resource. NO OTHER LICENSE, EXPRESS OR IMPLIED, BY ESTOPPEL OR OTHERWISE TO ANY OTHER TI INTELLECTUAL PROPERTY RIGHT, AND NO LICENSE TO ANY TECHNOLOGY OR INTELLECTUAL PROPERTY RIGHT OF TI OR ANY THIRD PARTY IS GRANTED HEREIN, including but not limited to any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information regarding or referencing third-party products or services does not constitute a license to use such products or services, or a warranty or endorsement thereof. Use of TI Resources may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

TI RESOURCES ARE PROVIDED "AS IS" AND WITH ALL FAULTS. TI DISCLAIMS ALL OTHER WARRANTIES OR REPRESENTATIONS, EXPRESS OR IMPLIED, REGARDING RESOURCES OR USE THEREOF, INCLUDING BUT NOT LIMITED TO ACCURACY OR COMPLETENESS, TITLE, ANY EPIDEMIC FAILURE WARRANTY AND ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND NON-INFRINGEMENT OF ANY THIRD PARTY INTELLECTUAL PROPERTY RIGHTS. TI SHALL NOT BE LIABLE FOR AND SHALL NOT DEFEND OR INDEMNIFY DESIGNER AGAINST ANY CLAIM, INCLUDING BUT NOT LIMITED TO ANY INFRINGEMENT CLAIM THAT RELATES TO OR IS BASED ON ANY COMBINATION OF PRODUCTS EVEN IF DESCRIBED IN TI RESOURCES OR OTHERWISE. IN NO EVENT SHALL TI BE LIABLE FOR ANY ACTUAL, DIRECT, SPECIAL, COLLATERAL, INDIRECT, PUNITIVE, INCIDENTAL, CONSEQUENTIAL OR EXEMPLARY DAMAGES IN CONNECTION WITH OR ARISING OUT OF TI RESOURCES OR USE THEREOF, AND REGARDLESS OF WHETHER TI HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES.

Unless TI has explicitly designated an individual product as meeting the requirements of a particular industry standard (e.g., ISO/TS 16949 and ISO 26262), TI is not responsible for any failure to meet such industry standard requirements.

Where TI specifically promotes products as facilitating functional safety or as compliant with industry functional safety standards, such products are intended to help enable customers to design and create their own applications that meet applicable functional safety standards and requirements. Using products in an application does not by itself establish any safety features in the application. Designers must ensure compliance with safety-related requirements and standards applicable to their applications. Designer may not use any TI products in life-critical medical equipment unless authorized officers of the parties have executed a special contract specifically governing such use. Life-critical medical equipment is medical equipment where failure of such equipment would cause serious bodily injury or death (e.g., life support, pacemakers, defibrillators, heart pumps, neurostimulators, and implantables). Such equipment includes, without limitation, all medical devices identified by the U.S. Food and Drug Administration as Class III devices and equivalent classifications outside the U.S.

TI may expressly designate certain products as completing a particular qualification (e.g., Q100, Military Grade, or Enhanced Product). Designers agree that it has the necessary expertise to select the product with the appropriate qualification designation for their applications and that proper product selection is at Designers' own risk. Designers are solely responsible for compliance with all legal and regulatory requirements in connection with such selection.

Designer will fully indemnify TI and its representatives against any damages, costs, losses, and/or liabilities arising out of Designer's noncompliance with the terms and provisions of this Notice.

> Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2017, Texas Instruments Incorporated